

Vishay Semiconductors

Small Signal Switching Diodes, Low Leakage Current

Features

- · Silicon planar diodes
- · Very low reverse current
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





Applications

Protection circuits, time delay circuits, peak follower circuits, logarithmic amplifiers



Mechanical Data

Case: MiniMELF SOD-80 Weight: approx. 31 mg

Cathode band color: black Packaging codes/options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks
BAQ33	V _{RRM} = 40 V	BAQ33-GS18 or BAQ33-GS08	Tape and Reel
BAQ34	V _{RRM} = 70 V	BAQ34-GS18 or BAQ34-GS08	Tape and Reel
BAQ35	V _{RRM} = 140 V	BAQ35-GS18 or BAQ35-GS08	Tape and Reel

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
		BAQ33	V _R	30	V
Reverse voltage		BAQ34	V _R	60	V
		BAQ35	V _R	125	V
Peak forward surge current	t _p = 1 μs		I _{FSM}	2	Α
Forward current			I _F	200	mA

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	On PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	500	K/W
Junction temperature		Tj	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

BAQ33, BAQ34, BAQ35

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Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 100 mA		V _F			1	V
Reverse current	E ≤ 300 lx, rated V _R		I _R		1	3	nA
	$E \le 300 \text{ lx}$, rated V_R , $T_j = 125 ^{\circ}\text{C}$		I _R			0.5	μΑ
	$E \le 300 \text{ lx}, V_R = 15 \text{ V}$	BAQ33	I _R		0.5	1	nA
	$E \le 3001 \text{ x}, V_R = 30 \text{ V}$	BAQ34	I _R		0.5	1	nA
	$E \le 300 \text{ lx}, V_R = 60 \text{ V}$	BAQ35	I _R		0.5	1	nA
	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	BAQ33	$V_{(BR)}$	40			V
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	BAQ34	V _(BR)	70			V
		BAQ35	V _(BR)	140			V
Diode capacitance	V _R = 0, f = 1 MHz		C _D			3	pF

Typical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

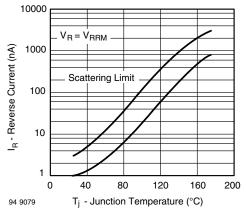


Figure 1. Reverse Current vs. Junction Temperature

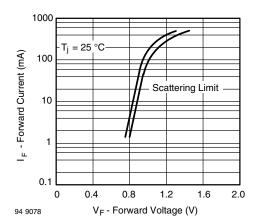
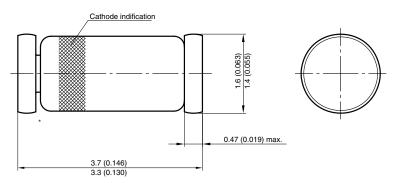


Figure 2. Forward Current vs. Forward Voltage

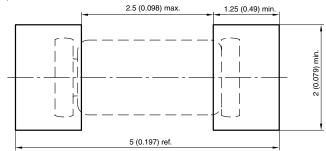
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Package Dimensions in millimeters (inches): MiniMELF SOD-80



^{*} The gap between plug and glass can be either on cathode or anode side

Foot print recommendation:



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